

# BCR10CM-16LH

800V - 10A - Triac

Medium Power Use

R07DS0320EJ0300

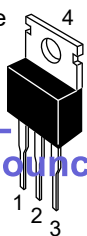
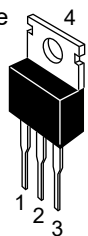
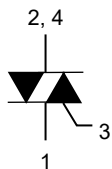
Rev.3.00

Feb. 1, 2019

## Features

- $I_T (RMS)$  : 10 A
- $V_{DRM}$  : 800 V
- $I_{FGT}$ ,  $I_{RGT}$ ,  $I_{RGT III}$ : 50 mA or 35 mA ( $I_{GT}$  item:1)
- $T_j$ : 150°C
- Planar Passivation Type
- High Commutation

## Outline

RENESAS Package code: PRSS0004AG-A (Package name: TO-220AB) Ordering code #BB0 	RENESAS Package code: PRSS0004AT-A (Package name: TO-220ABA) Ordering code #BH0 	
EOL announced		1. T <sub>1</sub> Terminal 2. T <sub>2</sub> Terminal 3. Gate Terminal 4. T <sub>2</sub> Terminal

## Application

Power supply, motor control, heater control, solenoid control, and other general purpose AC control applications.

## Maximum Ratings

Parameter	Symbol	Voltage class	
		16	Unit
Repetitive peak off-state voltage <sup>Note1</sup>	$V_{DRM}$	800	V
Non-repetitive peak off-state voltage <sup>Note1</sup>	$V_{DSM}$	960	V

Parameter	Symbol	Ratings	Unit	Conditions
RMS on-state current	$I_T (RMS)$	10	A	Commercial frequency, sine full wave 360°conduction, $T_c = 128^\circ\text{C}$ <sup>Note3</sup>
Surge on-state current	$I_{TSM}$	100	A	60 Hz sinewave 1 full cycle, peak value, non-repetitive
$I^2t$ for fusion	$I^2t$	41.6	A <sup>2</sup> s	Value corresponding to 1 cycle of half wave 60 Hz, surge on-state current
Peak gate power dissipation	$P_{GM}$	5	W	
Average gate power dissipation	$P_{G(AV)}$	0.5	W	
Peak gate voltage	$V_{GM}$	10	V	
Peak gate current	$I_{GM}$	2	A	
Junction Temperature	$T_j$	-40 to +150	°C	
Storage temperature	$T_{stg}$	-40 to +150	°C	

## Electrical Characteristics

Parameter	Symbol	BCR10CM-16LH-1 (I <sub>GT</sub> item:1)			BCR10CM-16LH			Unit	Test conditions	
		Min.	Typ.	Max.	Min.	Typ.	Max.			
Repetitive peak off-state current	I <sub>DRM</sub>	—	—	2.0	—	—	2.0	mA	T <sub>j</sub> = 150°C V <sub>DRM</sub> applied	
On-state voltage	V <sub>TM</sub>	—	—	1.5	—	—	1.5	V	T <sub>c</sub> = 25°C, I <sub>TM</sub> = 15 A instantaneous measurement	
Gate trigger voltage <sup>Note2</sup>	I	V <sub>FGTI</sub>	—	—	1.5	—	—	1.5	V	T <sub>j</sub> = 25°C, V <sub>D</sub> = 6 V R <sub>L</sub> = 6 Ω, R <sub>G</sub> = 330 Ω
	II	V <sub>RGTI</sub>	—	—	1.5	—	—	1.5	V	
	III	V <sub>RGTIII</sub>	—	—	1.5	—	—	1.5	V	
Gate trigger current <sup>Note2</sup>	I	I <sub>FGTI</sub>	—	—	35	—	—	50	mA	T <sub>j</sub> = 25°C, V <sub>D</sub> = 6 V R <sub>L</sub> = 6 Ω, R <sub>G</sub> = 330 Ω
	II	I <sub>RGTI</sub>	—	—	35	—	—	50	mA	
	III	I <sub>RGTIII</sub>	—	—	35	—	—	50	mA	
Gate non-trigger voltage	V <sub>GD</sub>	0.2	—	—	0.2	—	—	V	T <sub>j</sub> = 125°C V <sub>D</sub> = 1/2 V <sub>DRM</sub>	
		0.1	—	—	0.1	—	—	V	T <sub>j</sub> = 150°C V <sub>D</sub> = 1/2 V <sub>DRM</sub>	
Thermal resistance	R <sub>th(j-c)</sub>	—	—	1.8	—	—	1.8	°C/W	Junction to case <sup>Note3,4</sup>	
Critical-rate of fall of on-state commutating current <sup>Note5</sup>	(di/dt) <sub>c</sub>	6	—	—	10	—	—	A/ms	T <sub>j</sub> = 125°C (dv/dt) <sub>c</sub> < 100 V/μs	

Notes: 1. Gate open.

2. Measurement using the gate trigger characteristics measurement circuit.

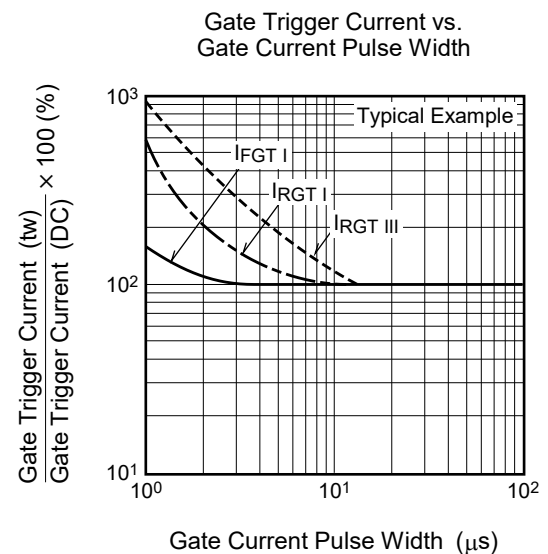
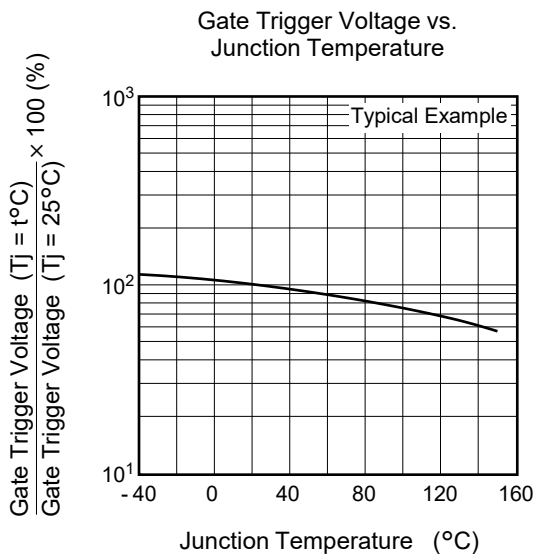
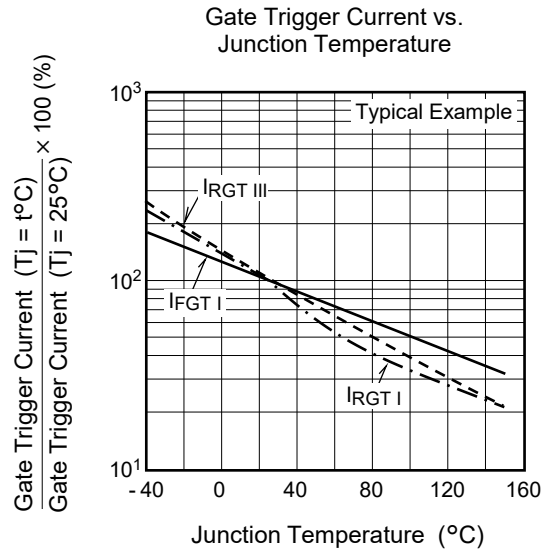
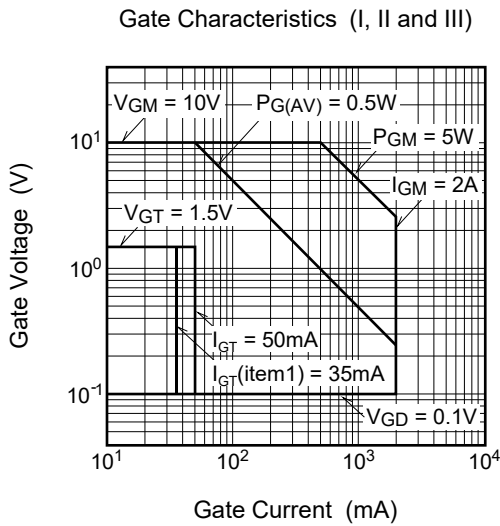
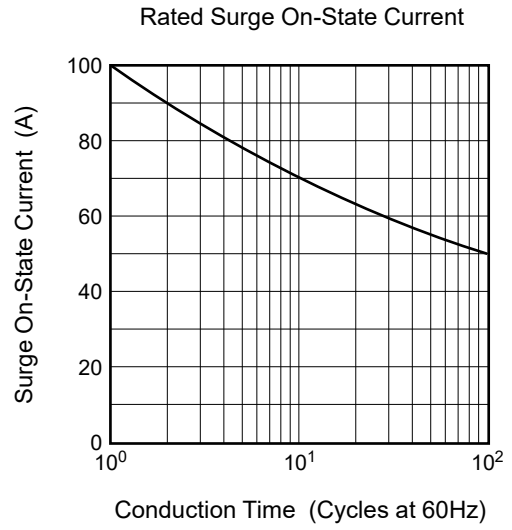
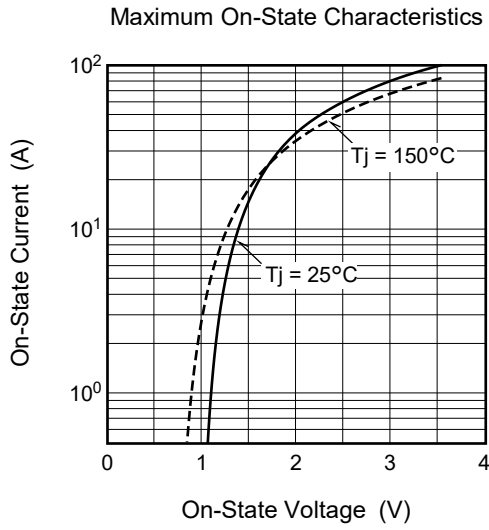
3. Case temperature is measured at the T<sub>2</sub> tab 1.5 mm away from the molded case.

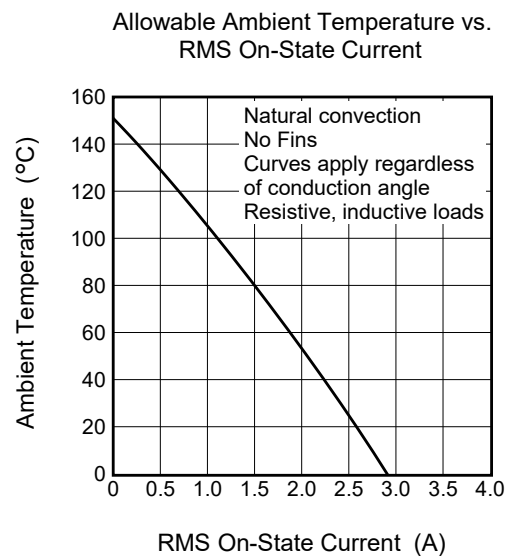
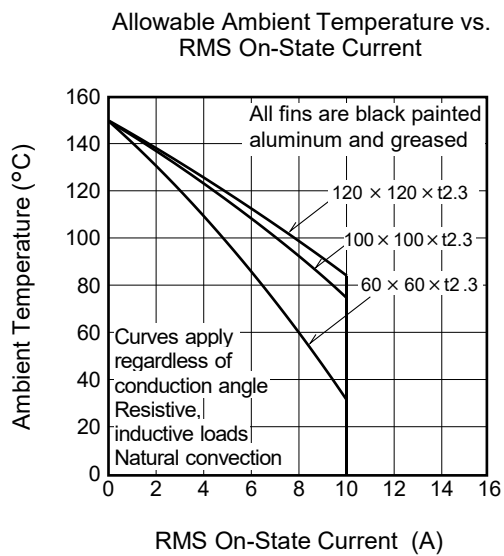
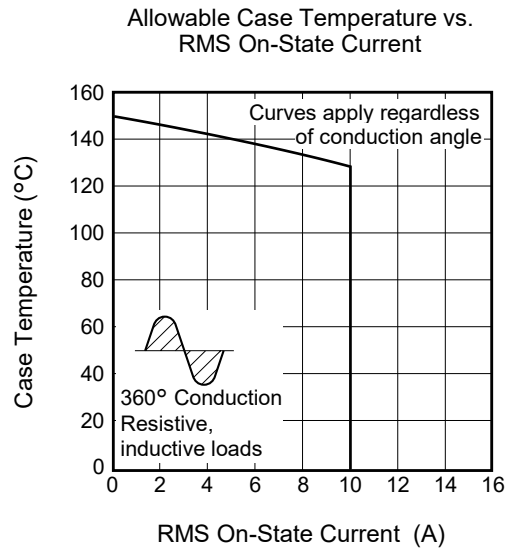
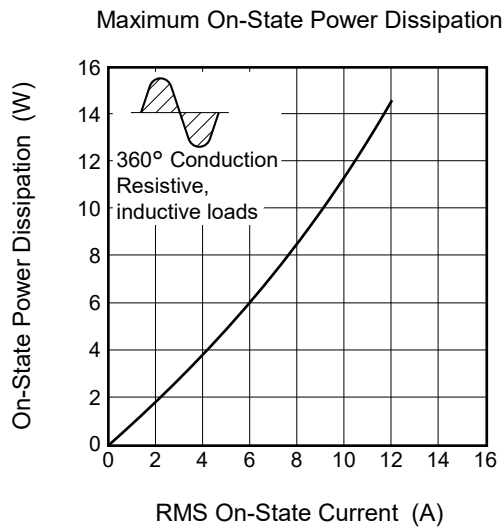
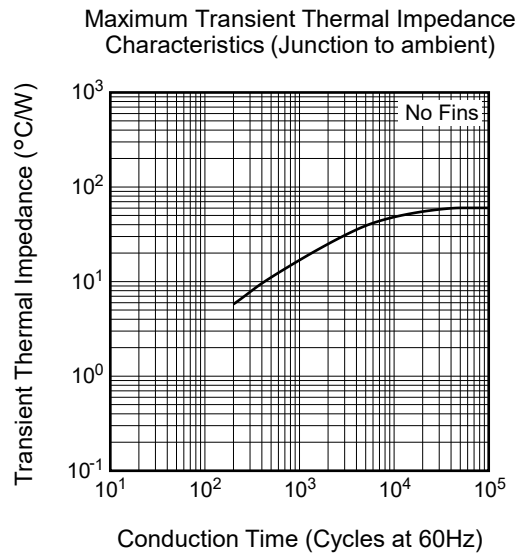
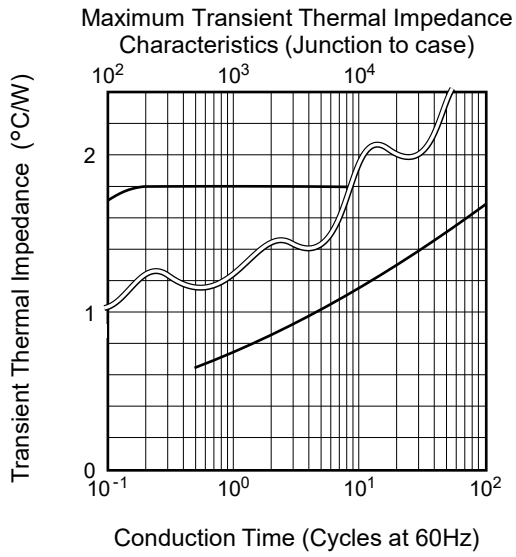
4. The contact thermal resistance R<sub>th(c-f)</sub> in case of greasing is 1.0°C/W.

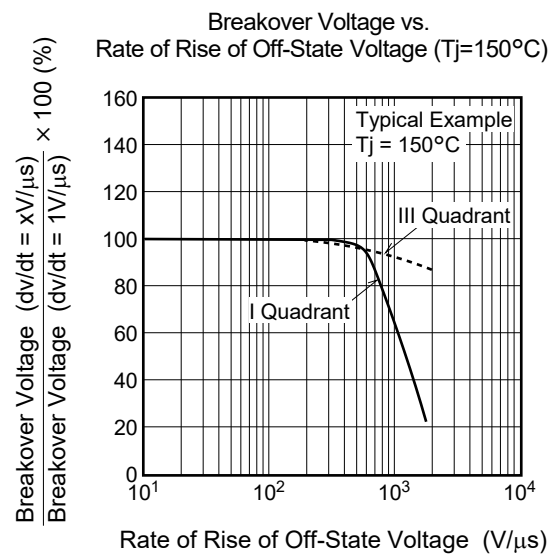
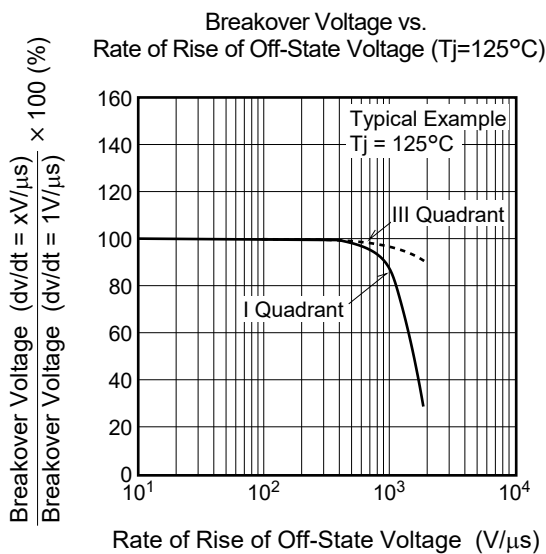
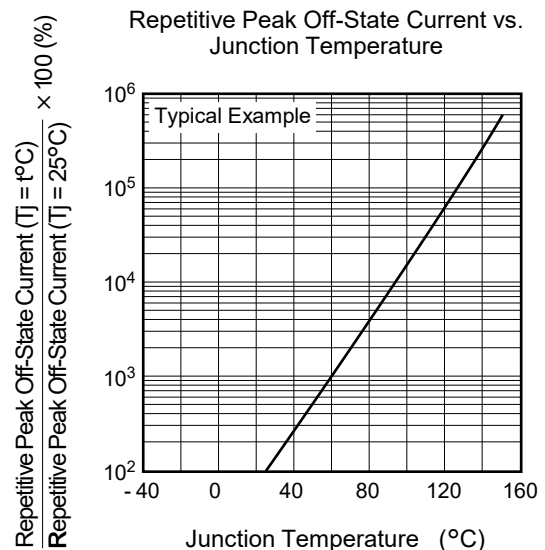
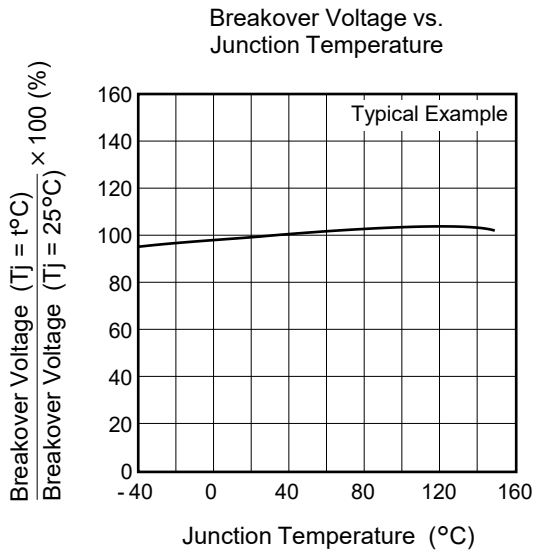
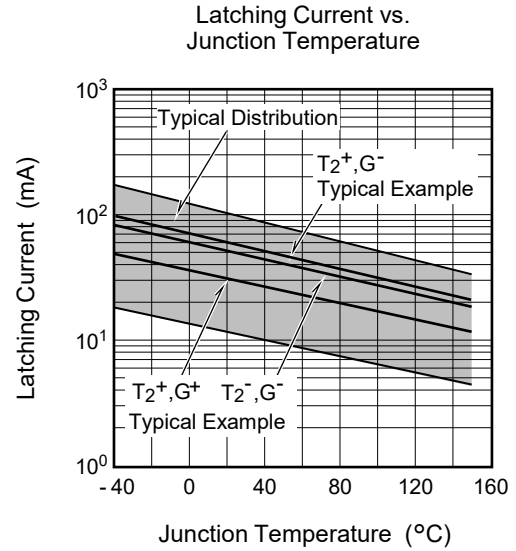
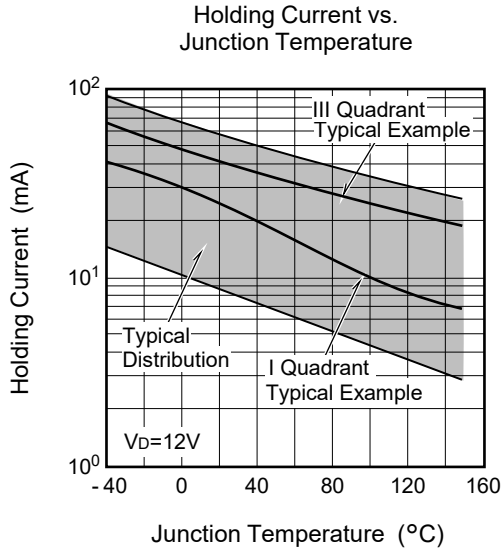
5. Test conditions of the critical-rate of fall of on-state commutation current are shown in the table below.

Test conditions	Commutating voltage and current waveforms (inductive load)
1. Junction temperature T <sub>j</sub> = 125°C 2. Peak off-state voltage V <sub>D</sub> = 400 V 3. Rate of rise of off-state commutating voltage (dv/dt) <sub>c</sub> < 100 V/μs	

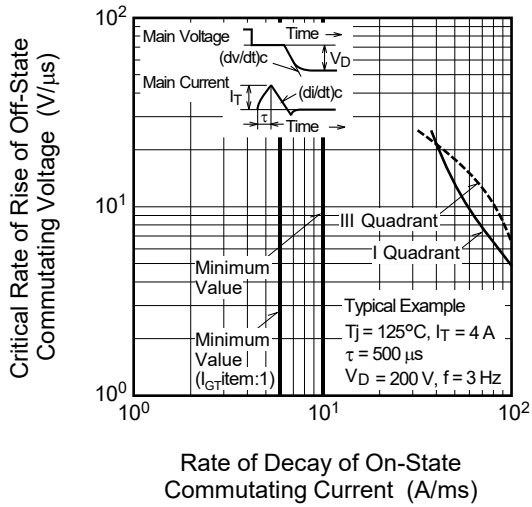
Performance Curves



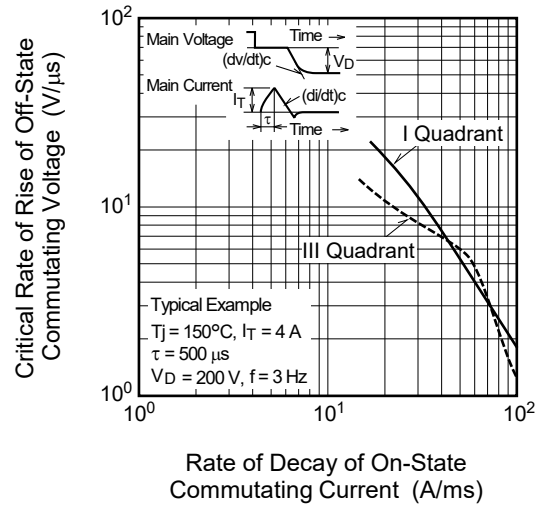




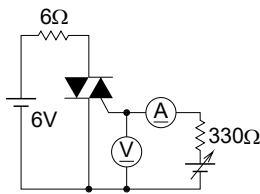
Commutation Characteristics (Tj=125°C)



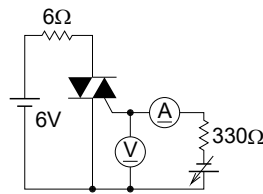
Commutation Characteristics (Tj=150°C)



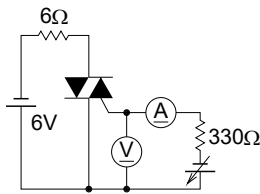
Gate Trigger Characteristics Test Circuits



Test Procedure I

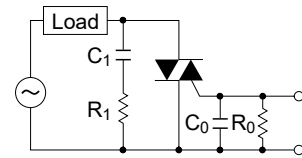


Test Procedure II



Test Procedure III

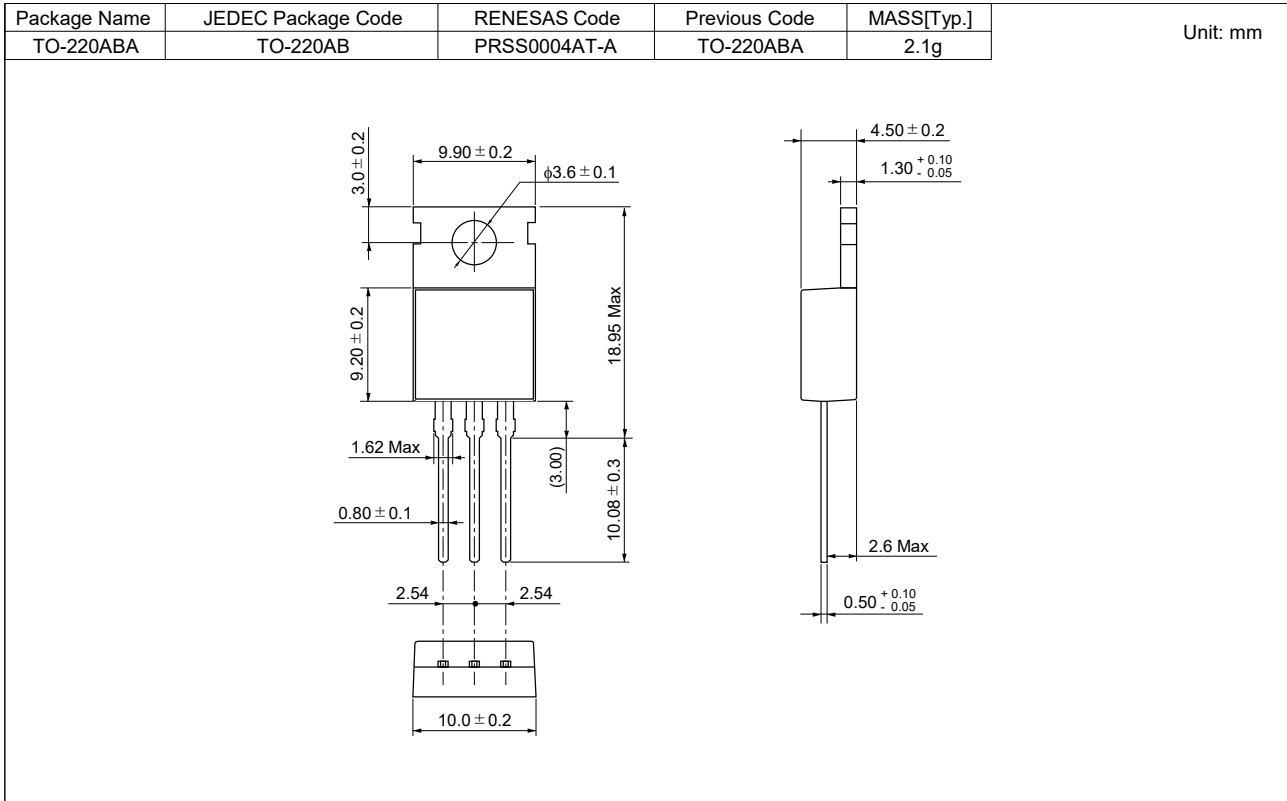
Recommended peripheral components for Triac



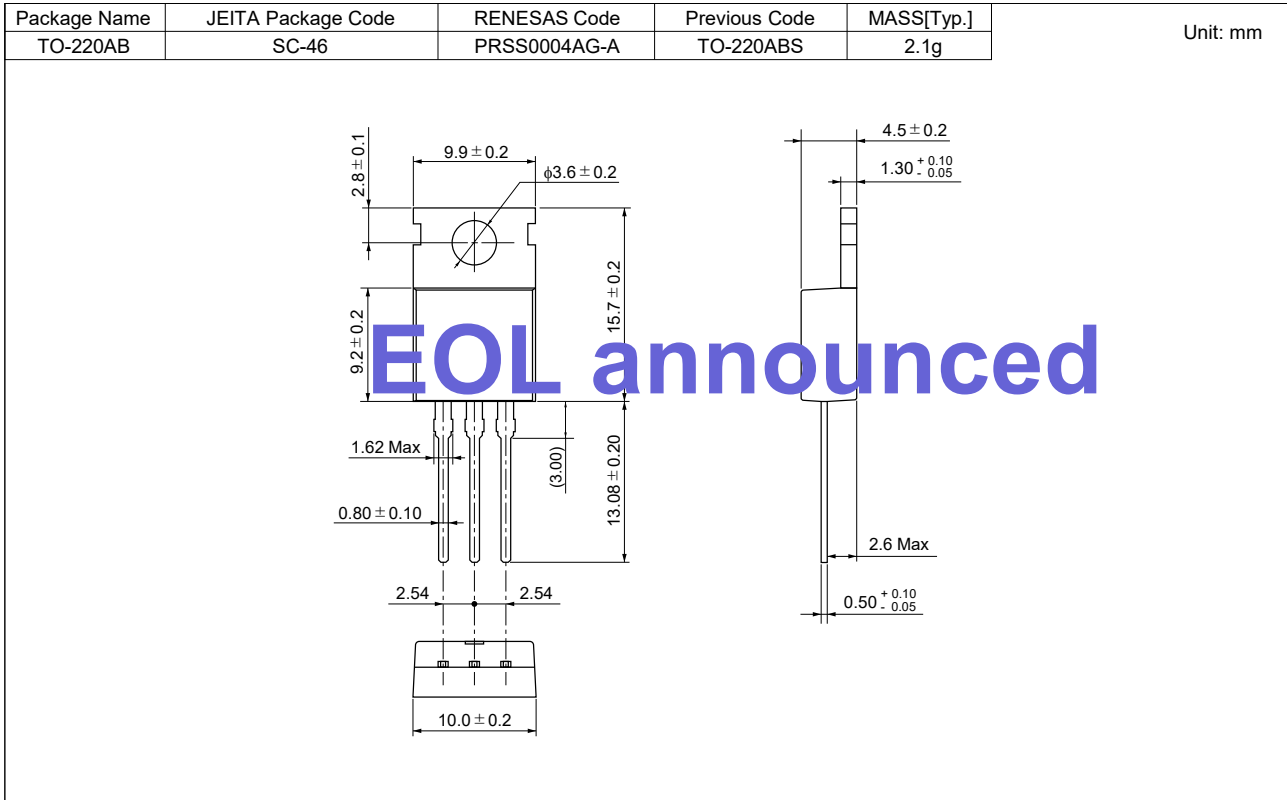
$C_1 = 0.1 \text{ to } 0.47 \mu\text{F}$      $C_0 = 0.1 \mu\text{F}$   
 $R_1 = 47 \text{ to } 100 \Omega$      $R_0 = 100 \Omega$

### Package Dimensions

Ordering code: #BH0



Ordering code: #BB0



## Ordering Information

Orderable Part Number	Package	Quantity <sup>Note6</sup>	Remark	Status
BCR10CM-16LH#BH0	TO-220ABA	50 pcs./ tube	Straight type	Mass Production
BCR10CM-16LH-1#BH0	TO-220ABA	50 pcs./ tube	Straight type, I <sub>GT</sub> item:1	
BCR10CM-16LH#BB0	TO-220ABS	50 pcs./ tube	Straight type	EOL announced
BCR10CM-16LH-1#BB0	TO-220ABS	50 pcs./ tube	Straight type, I <sub>GT</sub> item:1	

Notes: 6. Please confirm the specification about the shipping in detail.



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**Renesas Electronics America Inc.**  
1001 Murphy Ranch Road, Milpitas, CA 95035, U.S.A.  
Tel: +1-408-432-8888, Fax: +1-408-434-5351

**Renesas Electronics Canada Limited**  
9251 Yonge Street, Suite 8309 Richmond Hill, Ontario Canada L4C 9T3  
Tel: +1-905-237-2004

**Renesas Electronics Europe Limited**  
Dukes Meadow, Millboard Road, Bourne End, Buckinghamshire, SL8 5FH, U.K  
Tel: +44-1628-651-700

**Renesas Electronics Europe GmbH**  
Arcadiastrasse 10, 40472 Düsseldorf, Germany  
Tel: +49-211-6503-0, Fax: +49-211-6503-1327

**Renesas Electronics (China) Co., Ltd.**  
Room 1709 Quantum Plaza, No.27 ZhichunLu, Haidian District, Beijing, 100191 P. R. China  
Tel: +86-10-8235-1155, Fax: +86-10-8235-7679

**Renesas Electronics (Shanghai) Co., Ltd.**  
Unit 301, Tower A, Central Towers, 555 Langao Road, Putuo District, Shanghai, 200333 P. R. China  
Tel: +86-21-2226-0888, Fax: +86-21-2226-0999

**Renesas Electronics Hong Kong Limited**  
Unit 1601-1611, 16/F., Tower 2, Grand Century Place, 193 Prince Edward Road West, Mongkok, Kowloon, Hong Kong  
Tel: +852-2265-6688, Fax: +852 2886-9022

**Renesas Electronics Taiwan Co., Ltd.**  
13F, No. 363, Fu Shing North Road, Taipei 10543, Taiwan  
Tel: +886-2-8175-9600, Fax: +886 2-8175-9670

**Renesas Electronics Singapore Pte. Ltd.**  
80 Bendemeer Road, Unit #06-02 Hyflux Innovation Centre, Singapore 339949  
Tel: +65-6213-0200, Fax: +65-6213-0300

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Unit 1207, Block B, Menara Amcorp, Amcorp Trade Centre, No. 18, Jln Persiaran Barat, 46050 Petaling Jaya, Selangor Darul Ehsan, Malaysia  
Tel: +60-3-7955-9390, Fax: +60-3-7955-9510

**Renesas Electronics India Pvt. Ltd.**  
No.777C, 100 Feet Road, HAL 2nd Stage, Indiranagar, Bangalore 560 038, India  
Tel: +91-80-67208700, Fax: +91-80-67208777

**Renesas Electronics Korea Co., Ltd.**  
17F, KAMCO Yangjae Tower, 262, Gangnam-daero, Gangnam-gu, Seoul, 06265 Korea  
Tel: +82-2-558-3737, Fax: +82-2-558-5338